P29FCT818/A (P29PCT818/A) HIGH SPEED DIAGNOSTIC SCAN REGISTERS



FEATURES

- Function, Pinout, and Drive Compatible with the FCT and F Logic
- FCT-C speed at 9.0ns max. (Com'l) FCT-A speed at 13.0ns max. (Com'l)
- CMOS V_{OH} Levels for Low Power Consumption - Typically 1/3 of FAST Bipolar Logic
- Edge-rate Control Circuitry for Significantly Improved Noise Characteristics
- ESD protection exceeds 2000V

- Inputs and Outputs Interface Directly with TTL, NMOS, and CMOS Devices
- **Outputs Meet Levels Required for CMOS Static** RAM Low Power Standby Mode
- 24 mA Sink Current (Com'l), 20 mA (Mil) 3 mA Source Current (Com'i), 3 mA (Mii)
- High Speed 8-Bit General Purpose Registers
- High Speed 8-Bit Serial Scan Registers — Expandable to Wider Widths
- Functionally Equivalent to Bipolar 29818 Type Devices
- Manufactured in 0.8 micron PACE Technology™

DESCRIPTION

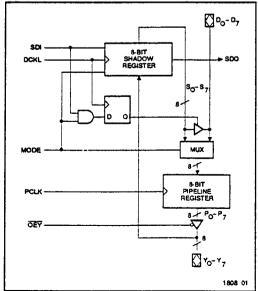
The 'FCT818 each contain a high speed 8-bit generalpurpose data pipeline register and a high speed 8-bit shadow register. The general-purpose register can be used in an 8-bit wide data path for a normal system application. The shadow register is designed for applications, such as diagnostics in sequential circuits, where it is desirable to load known data at a specific location in the circuit and to read the data at that location.

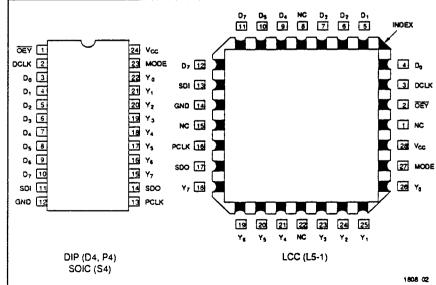
The shadow registers can load data from the output of the 'FCT818, and can be used as a right-shift register with bitserial input SDI and output SDO, using DCLK. The data register input is multiplexed to enable loading from the shadow register or from the data input pins using PCLK. Note that data can be loaded simultaneously from the shadow register to the pipeline register, and from the

pipeline register to the shadow register provided set-up and hold time requirements are satisfied with respect to the two independent clock inputs.

In a typical application, the general-purpose register in the 'FCT818 replaces an 8-bit data register in the normal data path of a system. The shadow register is placed in an auxiliary bit-serial loop which is used for diagnostics. During diagnostic operation, data is shifted serially into the shadow register, then transferred to the general-purpose register to load a known value into the data path. To read the contents at that point in the data path, the data is transferred from the data register into the shadow register, then shifted serially in the auxiliary diagnostic loop to make it accessible to the diagnostics controller. This data is then compared with the expected value to diagnose faulty operation of the sequential circuit.

FUNCTIONAL BLOCK DIAGRAM PIN CONFIGURATIONS







Means Quality, Service and Speed

The contents of the shadow register can also be output by enabling the 8-bit wide D input/output port. In an application such as micro-program testing, the microinstruction register is formed using the general-purpose registers of 'FCT818 devices with cascaded shadow registers. To modify the microinstruction register, the corrected instruction word is shifted serially into the shadow registers and then transferred into the data registers. This word is also loaded easily into the Writeable Control Store (WCS) by enabling the D output from the shadow registers.

The 'FCT818 are manufactured with PACE Technology which is Performance Advanced CMOS Engineered to use 0.8 micron effective channel lengths giving 500

picoseconds loaded* internal gate delays. PACE Technology includes two-level metal and epitaxial substrates. In addition to very high performance and very high density, this technology features latch-up protection and single-event-upset protection, and is supported by a Class 1 facility for volume production.

The 'FCT818 are available in 24-pin 300 mil DIP and in 28-Pad 450 x 450 mil LCC packages providing excellent board level densities.

For a fan-in/fan-out of 4 at 85°C junction temperature and 5.0V supply. For a fan-in/fan-out of 1, the internal gate delay is 200 picoseconds at room temperature and 5.0V supply.



DC ELECTRICAL CHARACTERISTICS (Over recommended operating conditions)

Symbol	Parameter	Min	Typ¹	Max	Units	V _{cc}	Conditions
V _{IH}	Input HIGH Voltage	2.0			٧		
V _{iL}	Input LOW Voltage			0.8	٧		
V _H	Hysteresis		0.35		٧		All inputs
V _{CD}	Input Clamp Diode Voltage		-0.7	-1.2	٧	MIN	I _{IN} = -18mA
V _{OH}	Output HIGH Voltage Military/Commercial (CMOS) Military/Commercial (Outputs D0-D7,SD0) Military (TTL) Commercial (TTL)	V _{cc} - 0.2 2.4 2.4 2.4	V _{cc} 4.3 4.3 4.3		V V V	MIN MIN MIN MIN	$I_{OH} = -300\mu A$ $I_{OH} = -1mA$ $I_{OH} = -3mA$ $I_{OH} = -3mA$
V _{OL}	Output LOW Voltage Military/Commercial (CMOS) Military (Outputs D0–D7,SD0) Commercial (Outputs D0–D7,SD0) Military (TTL) Commercial (TTL)		V _{cc} 0.3 0.3 0.3 0.3	0.2 0.5 0.5 0.5 0.5	>>>>>	MIN MIN MIN MIN MIN	l _{OL} = 300μA l _{OL} = 4mA l _{OL} = 8mA l _{OL} = 20mA l _{OL} = 24mA
I _{tH}	Input HIGH Current			5	μА	MAX	$V_{iN} = V_{CC}$
I,_	Input LOW Current			- 5	μА	MAX	V _{IN} = GND
I _{IH}	Input HIGH Current ³			5	μА	MAX	$V_{IN} = 2.7V$
1,_	Input LOW Current ³			- 5	μА	MAX	$V_{IN} = 0.5V$
охн	Off State I _{OUT} HIGH-Level Output Current			10	μА	MAX	$V_{OUT} = V_{CC}$
lozi	Off State I _{OUT} LOW-Level Output Current			-10	μА	MAX	V _{OUT} = GND
I _{OZH}	Off State I _{OUT} HIGH-Level Output Current ³			10			$V_{OUT} = 2.7V$
OZL	Off State I _{OUT} LOW-Level Output Current ³			-10			$V_{OUT} = 0.5V$
los	Output Short Circuit Current ²				mA	MAX	$V_{OUT} = 0.0V$
C _{IN}	Input Capacitance ³		5	10	pF		All inputs
C _{OUT}	Output Capacitance ³		9	12	pF	MAX	All outputs

Notes

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^{1.} Typical limits are at V_{cc} = 5.0V, T_{A} = +25°C ambient.

^{2.} Not more than one output should be shorted at a time. Duration of short should not exceed one second. The use of high speed test apparatus and/or sample and hold techniques are preferable in order to minimize internal chip heating and more accurately reflect

operational values. Otherwise prolonged shorting of a high output may raise the chip temperature well above normal and thereby cause invalid readings in other parameter tests. In any sequence of parameter tests, I_{os} tests should be performed last.

^{3.} This parameter is guaranteed but not tested.

ABSOLUTE MAXIMUM RATINGS^{1,2}

Symbol	Parameter	Value	Unit
T _{STG}	Storage Temperature	-65 to +150	°C
T _A	Ambient Temperature Under Bias	-65 to +135	°C
V _{cc}	V _{cc} Potential to Ground	-0.5 to +7.0	٧
I _{IN}	Input Current	-30 to +5.0	mA

м	٠	•	-	•

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Operation beyond the limits set forth in the above table may impair the useful life of the device. Unless otherwise noted, these limits are over the operating free-air temperature range.

Symbol	Parameter	Value	Unit
OUTPUT	Current Applied to Output	120	mA
Vin	Input Voltage	-0.5 to $V_{\infty} + 0.5$	٧
V _{out}	Voltage Applied to Output	-0.5 to $V_{\infty} + 0.5$	٧

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RECOMMENDED OPERATING CONDITIONS

Free Air Ambient Temperature	Min	Max
Military	-55°C	+125°C
Commercial	0°C	+70°C

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Supply Voltage (V _{cc})	Min	Max
Military	+4.5V	+5.5V
Commercial	+4.75V	+5.25V

1808 Tbi 05

DC CHARACTERISTICS (Over recommended operating conditions unless otherwise specified.)

Symbol	Parameter	Typ¹	Max	Units	Conditions
18	Quiescent Power Supply Current (CMOS inputs)	0.003	0.5	mA	$V_{CC} = MAX$, $f_1 = 0$, Outputs Open, $V_{IN} \le 0.2V$ or $V_{IN} \ge V_{CC} - 0.2V$
Δl _{cc}	Quiescent Power Supply Current (TTL inputs)		2.0	mA	V_{CC} = MAX, Outputs Open, $f_1 = 0$, $V_{IN} = 3.4V$
I _{cco}	Dynamic Power Supply Current ³		0.25	mA/ mHz	$V_{\rm CC}$ = MAX, One Input Toggling, 50% Duty Cycle, $\overline{\rm OEY}$ = GND, Outputs Open, $V_{\rm IN} \le 0.2 {\rm V}$ or $V_{\rm IN} \ge V_{\rm CC} - 0.2 {\rm V}$
			5.3	mA	V_{cc} = MAX, f_0 = 10MHz, 50% Duty Cycle, Outputs Open, One Bit Toggling at f_1 = 5MHz, \overline{OEY} = GND, $V_{IN} \le 0.2V$ or $V_{IN} \ge V_{cc} - 0.2V$
l _c	I _c Total Power Supply Current ⁵		7.3	mA	V_{CC} = MAX, f_0 = 10MHz, 50% Duty Cycle, Outputs Open, One Bit Toggling at f_1 = 5MHz, \overline{OEY} = GND, V_{IN} = 3.4V or V_{IN} = GND
			17.84	mA	V_{CC} = MAX, f_0 = 10MHz, 50% Duty Cycle, Outputs Open, Eight Bits and Four Controls Toggling, \overline{OEY} = GND, f_1 = 5MHz, $V_{IN} \le 0.2V$ or $V_{IN} \ge V_{CC} - 0.2V$
			30.84	mA	V_{CC} = MAX, f_0 = 10MHz, 50% Duty Cycle, Outputs Open, Eight Bits and Four Controls Toggling, \overline{OEY} = GND, f_1 = 5MHz, and V_{IN} = 3.4V or V_{IN} = GND

Notes can be found at the end of this data sheet.

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^{2.} Unused inputs must always be connected to an appropriate logic voltage level, preferably either $\rm V_{cc}$ or ground.

AC CHARACTERISTICS (Over recommended operating conditions)

			'FC	Г818		'FCT818A					
Symbol	Parameter	rameter MIL COM'L		MIL COM'L			Units	Fig. No.			
		Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.		
t _{PD}	PCLK TO YX MODE to SDO SDI to SDO DCLK to SDO		18 18 18 30		13 16 16 25		12 18 18 30		9 16 15 25	ns ns ns	5 6 3 5
t _s	Dx to PCLK MODE to PCLK Yx to DCLK MODE to DCLK SDI to DCLK DCLK to PCLK DCLK to DCLK	10 15 5 12 10 15 45		8 15 5 12 10 15 40		6 15 5 12 10 15 45		4 15 5 12 10 15 40		ns ns ns ns ns ns	4
t _H	Dx to PCLK MODE to PCLK Yx to DCLK MODE to DCLK SDI to DCLK	2 0 5 5 0		2 0 5 2 0		2 0 5 5		2 0 5 2 0		ns ns ns ns	4
t _{PLZ}	OEY to Yx DCLK to Dx		20 45		15 45		20 45		15 45	ns ns	7 5
t _{PHZ}	OEY to Yx DCLK to Dx		30 90		25 85	-	30 90		25 80	ns ns	8 5
t _{PZL}	OEY to Yx DCLK to Dx		20 35		15 30		20 35		15 25	ns ns	7 5
t _{PZH}	OEY to Yx DCLK to Dx		20 30		15 25		20 30		15 25	ns ns	8 5
t _w	PCLK (High and Low) DCLK (High and Low)	15 25		15 25		15 25		10 15		ns ns	5 5

Note: AC Characteristics guaranteed with $C_L = 50 pF$ as shown in Figure 1.

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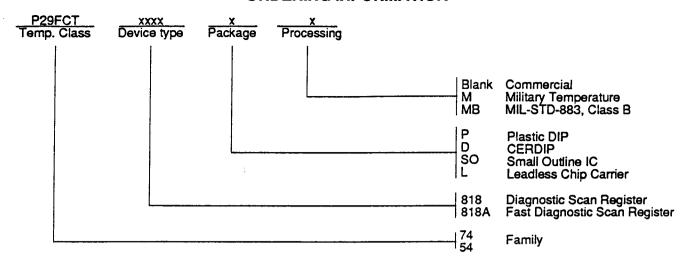
FUNCTION TABLE

	Inputs				Outputs	3		
MODE	SDI	DCLK	PCLK	SDO	Shadow Register	Pipeline Register	Operation	
L	X		Х	S ₇	S ₀ ←SDI S _i ←S _{I-1}	NA	Serial Shift; D ₇ -D ₀ Output Disabled	
L	X	X	۲	S ₇	NA	$P_i \leftarrow D_i$	Load Pipeline Register from Data Input	
H H	L H X	×	۲××	L H SDI	S ₁ ←Y ₁ Hold NA	NA NA P _i ←S _i	Load Shadow Register from Y Output Hold Shadow Register; D ₇ -D ₀ Output Enabled Load Pipeline Register from Shadow Register	

Note: NA = Not Applicable

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ORDERING INFORMATION



1808 03

Notes:

- 1. Typical values are at $V_{cc} = 5.0V$, +25°C ambient and maximum loading.
- 2. Per TTL driven input ($V_N = 3.4V$); all other inputs at V_{cc} or GND.
- 3. This parameter is not directly testable, but is derived for use in Total Power Supply calculations.
- 4. Values for these conditions are examples of the $I_{\rm cc}$ formula. These limits are guaranteed but not tested.

5.
$$I_{c} = I_{\text{OUMESCENT}} + I_{\text{INPUTS}} + I_{\text{DYNAMIC}}$$
 $I_{cc} = I_{cc} + \Delta I_{cc} D_{\text{H}} N_{\text{T}} + I_{cc0} (f_{\text{O}}/2 + f_{\text{1}} N_{\text{1}})$
 $I_{cc} = \text{Quiescent Current with CMOS input levels}$

ΔI_{cc} = Power Supply Current for a TTL High Input $(V_N = 3.4V)$

D_H = Duty Cycle for TTL Inputs High

N_T = Number of TTL Inputs at D_H

I_{cco} = Dynamic Current Caused by an Input Transition Pair (HLH or LHL)

= Clock Frequency for Register Devices (Zero for Non-Register Devices)

= Input Frequency

= Number of Inputs at f.

All currents are in milliamps and all frequencies are in megahertz.